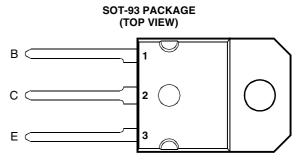
# **BOURNS®**

- Designed for Complementary Use with BDV64, BDV64A, BDV64B and BDV64C
- 125 W at 25°C Case Temperature
- 12 A Continuous Collector Current
- Minimum h<sub>FE</sub> of 1000 at 4 V, 5 A



Pin 2 is in electrical contact with the mounting base.

MDTRAAA

## absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT	
	BDV65		60		
Collector-base voltage (I <sub>E</sub> = 0)	BDV65A		80	V	
	BDV65B	Усво	100		
	BDV65C		120		
	BDV65		60		
Collector-emitter voltage (I <sub>B</sub> = 0)	BDV65A	V <sub>CEO</sub>	80	V	
	BDV65B		100		
	BDV65C		120		
Emitter-base voltage		V <sub>EBO</sub>	5	V	
Continuous collector current			12	Α	
Peak collector current (see Note 1)			15	Α	
Continuous base current		I <sub>B</sub>	0.5	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		P <sub>tot</sub>	125	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)		P <sub>tot</sub>	3.5	W	
Operating junction temperature range		T <sub>j</sub>	-65 to +150	°C	
Storage temperature range		T <sub>stg</sub>	-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds		$T_L$	260	°C	

NOTES: 1. This value applies for  $t_p \le 0.1$  ms, duty cycle  $\le 10\%$ 

- 2. Derate linearly to 150°C case temperature at the rate of 0.56 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 28 mW/°C.



# electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER TEST CONDITIONS		MIN	TYP	MAX	UNIT				
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 30 mA	I <sub>B</sub> = 0	(see Note 4)	BDV65 BDV65A BDV65B BDV65C	60 80 100 120			V
I <sub>CEO</sub>	Collector-emitter cut-off current	$V_{CB} = 30 \text{ V}$ $V_{CB} = 40 \text{ V}$ $V_{CB} = 50 \text{ V}$ $V_{CB} = 60 \text{ V}$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$		BDV65 BDV65A BDV65B BDV65C			2 2 2 2	mA
Ісво	Collector cut-off current	$\begin{array}{c} V_{CB} = \ 60 \ V \\ V_{CB} = \ 80 \ V \\ V_{CB} = \ 100 \ V \\ V_{CB} = \ 120 \ V \\ V_{CB} = \ 30 \ V \\ V_{CB} = \ 40 \ V \\ V_{CB} = \ 50 \ V \\ V_{CB} = \ 60 \ V \end{array}$	$I_{E} = 0$	$T_C = 150$ °C $T_C = 150$ °C $T_C = 150$ °C $T_C = 150$ °C	BDV65 BDV65A BDV65B BDV65C BDV65 BDV65A BDV65B BDV65C			0.4 0.4 0.4 0.4 2 2 2	mA
I <sub>EBO</sub>	Emitter cut-off current Forward current	V <sub>EB</sub> = 5 V	I <sub>C</sub> = 0					5	mA
h <sub>FE</sub>	transfer ratio	V <sub>CE</sub> = 4 V	I <sub>C</sub> = 5 A	(see Notes 4 and	5)	1000			
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	I <sub>B</sub> = 20 mA	I <sub>C</sub> = 5 A	(see Notes 4 and	5)			2	V
V <sub>BE</sub>	Base-emitter voltage	V <sub>CE</sub> = 4 V	I <sub>C</sub> = 5 A	(see Notes 4 and	5)			2.5	V
V <sub>EC</sub>	Parallel diode forward voltage	I <sub>E</sub> = 10 A	I <sub>B</sub> = 0	(see Notes 4 and	5)			3.5	٧

NOTES: 4. These parameters must be measured using pulse techniques,  $t_p = 300 \mu s$ , duty cycle  $\leq 2\%$ .

# thermal characteristics

-						
		PARAMETER	MIN	TYP	MAX	UNIT
Ī	$R_{\theta JC}$	Junction to case thermal resistance			1	°C/W
Ī	$R_{\theta JA}$	Junction to free air thermal resistance			35.7	°C/W

<sup>5.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

#### **TYPICAL CHARACTERISTICS**

# **TYPICAL DC CURRENT GAIN** vs **COLLECTOR CURRENT** TCS140AD 70000 -40°C 25°C = 100°C h<sub>FE</sub> - Typical DC Current Gain 10000 1000 = 300 µs, duty cycle < 2% 100 0.5 1.0 10 20 I<sub>c</sub> - Collector Current - A Figure 1.

**COLLECTOR-EMITTER SATURATION VOLTAGE** 

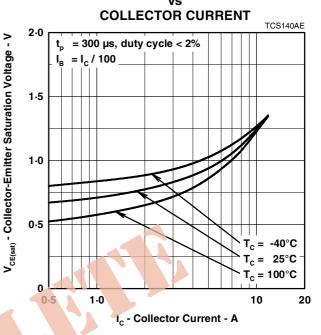
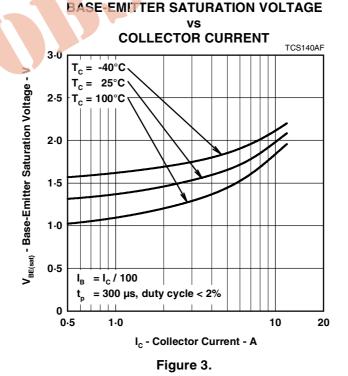


Figure 2.





PRODUCT INFORMATION

## THERMAL INFORMATION

#### **MAXIMUM POWER DISSIPATION**

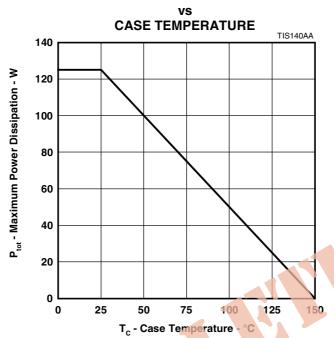


Figure 4.